



CYPRESS

PRELIMINARY

CY7C1360A/GVT71256D36

CY7C1362A/GVT71512D18

256K x 36/512K x 18 Pipelined SRAM

Features

- Fast access times: 2.5 ns, 3.0 ns, and 3.5 ns
- Fast clock speed: 225, 200, 166, and 150 MHz
- Fast OE access times: 2.5 ns, 3.0 ns, and 3.5 ns
- Optimal for depth expansion (one cycle chip deselect to eliminate bus contention)
- 3.3V -5% and +10% power supply
- 3.3V or 2.5V I/O supply
- 5V tolerant inputs except I/Os
- Clamp diodes to V_{SS} at all inputs and outputs
- Common data inputs and data outputs
- Byte Write Enable and Global Write control
- Multiple chip enables for depth expansion: three chip enables for TA package version and two chip enables for B and T package versions
- Address pipeline capability
- Address, data, and control registers
- Internally self-timed Write Cycle
- Burst control pins (interleaved or linear burst sequence)
- Automatic power-down for portable applications
- JTAG boundary scan for B and T package version
- Low profile 119-bump, 14-mm x 22-mm PBGA (Ball Grid Array) and 100-pin TQFP packages

Functional Description

The Cypress Synchronous Burst SRAM family employs high-speed, low-power CMOS designs using advanced triple-layer polysilicon, double-layer metal technology. Each memory cell consists of four transistors and two high-valued resistors.

The CY7C1360A/GVT71256D36 and CY7C1362A/GVT71512D18 SRAMs integrate 262,144x36 and 524,288x18 SRAM cells with advanced synchronous peripheral circuitry

and a 2-bit counter for internal burst operation. All synchronous inputs are gated by registers controlled by a positive-edge-triggered Clock Input (CLK). The synchronous inputs include all addresses, all data inputs, address-pipelining Chip Enable (\overline{CE}), depth-expansion Chip Enables (CE_2 and \overline{CE}_2), burst control inputs (\overline{ADSC} , \overline{ADSP} , and \overline{ADV}), Write Enables (\overline{BWA} , \overline{BWB} , \overline{BWC} , \overline{BWD} , and \overline{BWE}), and global write (\overline{GW}). However, the CE_2 chip enable input is only available for the TA package version.

Asynchronous inputs include the Output Enable (\overline{OE}) and burst mode control (MODE). The data outputs (Q), enabled by \overline{OE} , are also asynchronous.

Addresses and chip enables are registered with either Address Status Processor (\overline{ADSP}) or Address Status Controller (\overline{ADSC}) input pins. Subsequent burst addresses can be internally generated as controlled by the Burst Advance Pin (\overline{ADV}).

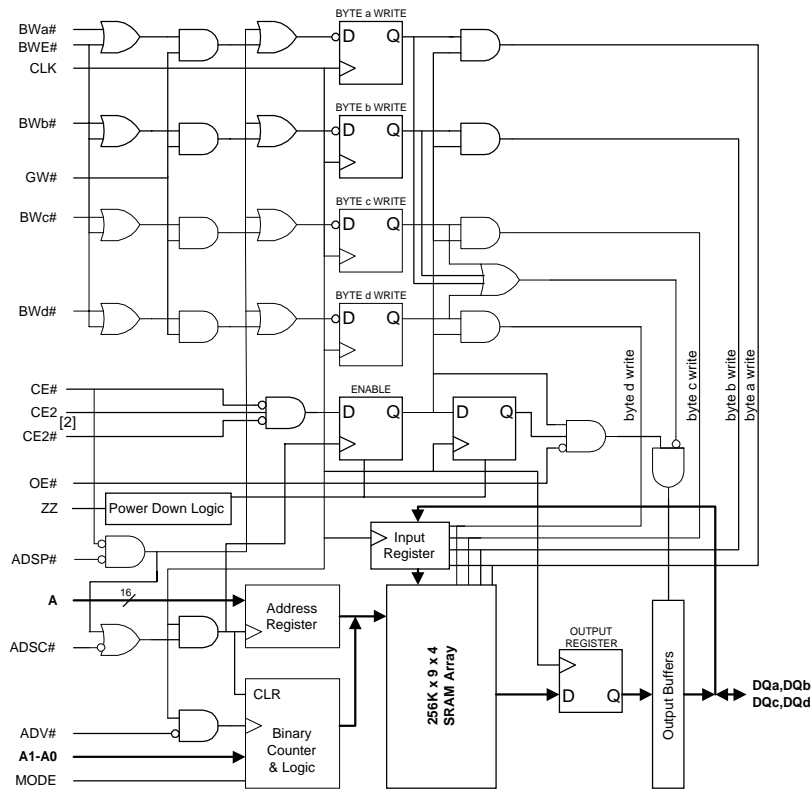
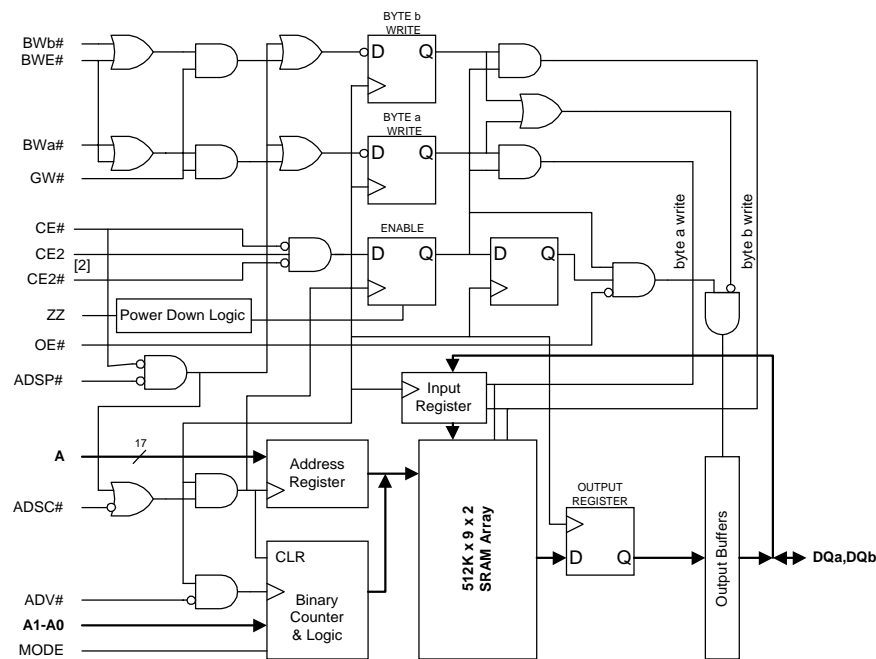
Address, data inputs, and write controls are registered on-chip to initiate self-timed WRITE cycle. WRITE cycles can be one to four bytes wide as controlled by the write control inputs. Individual byte write allows individual byte to be written. \overline{BWA} controls DQa. \overline{BWB} controls DQb. \overline{BWC} controls DQc. \overline{BWD} controls DQd. \overline{BWA} , \overline{BWB} , \overline{BWC} , and \overline{BWD} can be active only with \overline{BWE} being LOW. \overline{GW} being LOW causes all bytes to be written. The x18 version only has 18 data inputs/outputs (DQa and DQb) along with \overline{BWA} and \overline{BWB} (no \overline{BWC} , \overline{BWD} , DQc, and DQd).

For the B and T package versions, four pins are used to implement JTAG test capabilities: Test Mode Select (TMS), Test Data-In (TDI), Test Clock (TCK), and Test Data-Out (TDO). The JTAG circuitry is used to serially shift data to and from the device. JTAG inputs use LVTTTL/LVCMOS levels to shift data during this testing mode of operation. The TA package version does not offer the JTAG capability.

The CY7C1360A/GVT71256D36 and CY7C1362A/GVT71512D18 operate from a +3.3V power supply. All inputs and outputs are LVTTTL compatible.

Selection Guide

| | | 7C1360A-225 71256D36-4.4 7C1362A-225 71512D18-4.4 | 7C1360A-200 71256D36-5 7C1362A-200 71512D18-5 | 7C1360A-166 71256D36-6 7C1362A-166 71512D18-6 | 7C1360A-150 71256D36-6.7 7C1362A-150 71512D18-6.7 |
|-----------------------------------|------------|------------------------------------------------------------|--------------------------------------------------------|--------------------------------------------------------|------------------------------------------------------------|
| Maximum Access Time (ns) | | 2.5 | 3.0 | 3.5 | 3.5 |
| Maximum Operating Current (mA) | Commercial | 570 | 510 | 425 | 380 |
| Maximum CMOS Standby Current (mA) | | 10 | 10 | 10 | 10 |

Functional Block Diagram—256K x 36^[1]

Functional Block Diagram—512K x 18^[1]

Notes:

1. The Functional Block Diagram illustrates simplified device operation. See Truth Table, pin descriptions and timing diagrams for detailed information.
2. CE₂ is for TA version only.

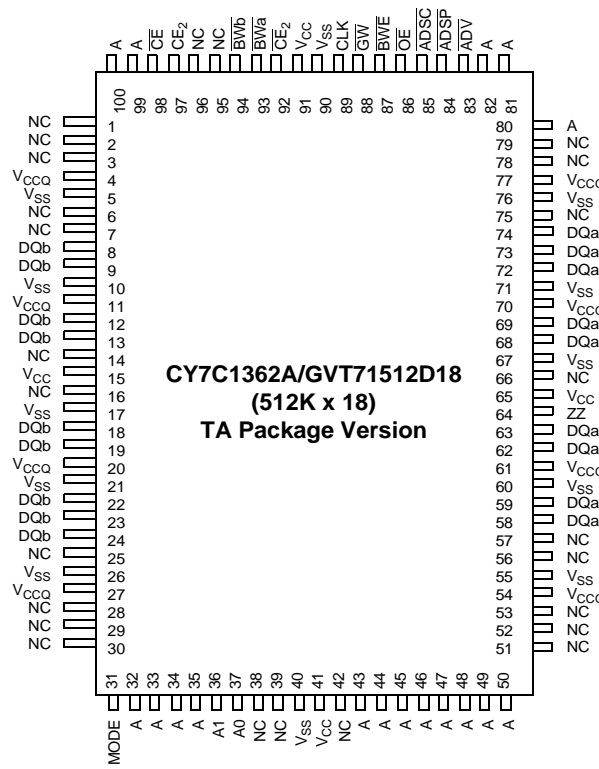
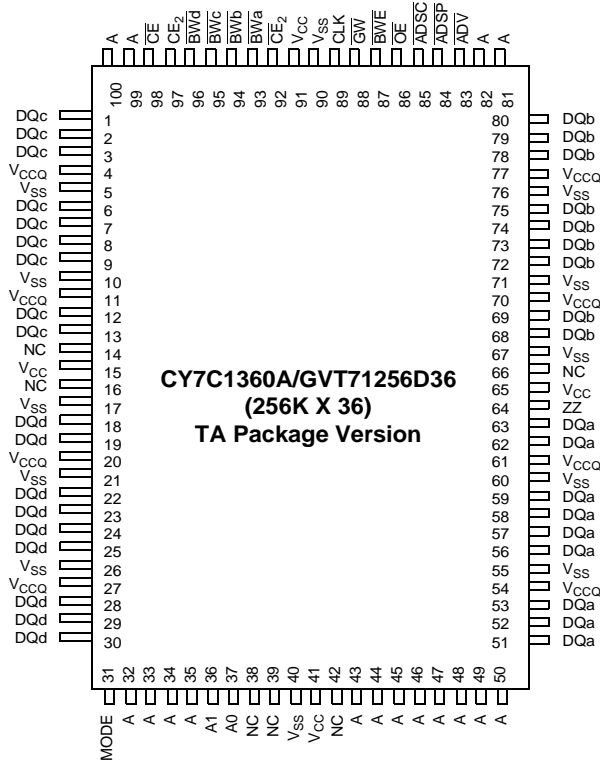
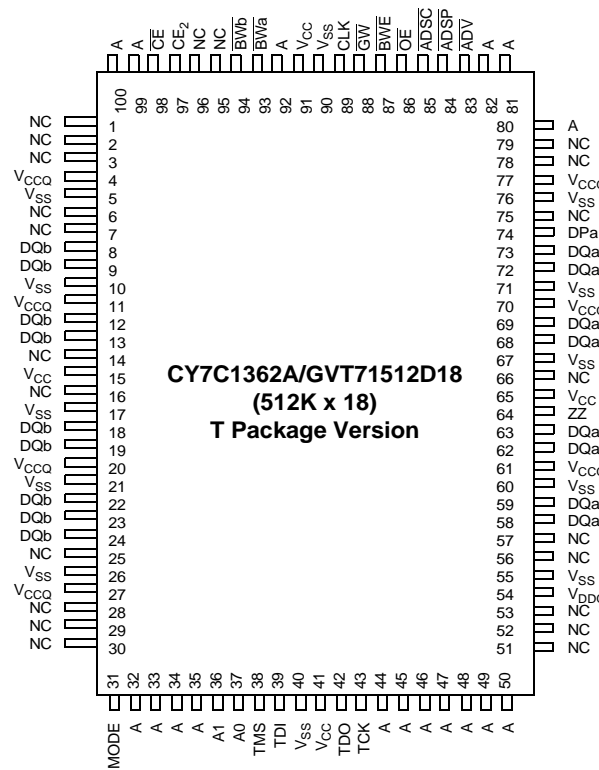
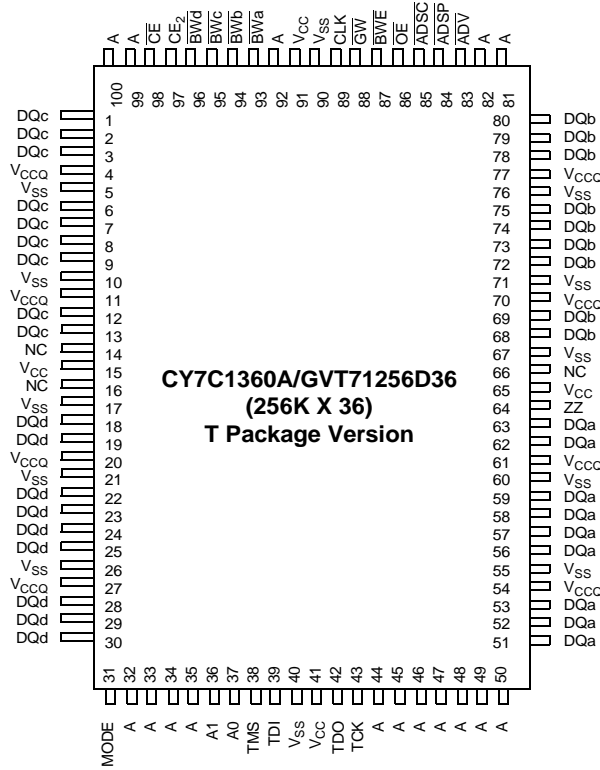


PRELIMINARY

**CY7C1360A/GVT71256D36
CY7C1362A/GVT71512D18**

Pin Configurations

**100-Pin TQFP
Top View**





Pin Configurations (continued)

**119-Ball BGA
Top View**

256Kx36

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
|----------|------------------|-----------------|-------------------------|--------------------------|-------------------------|-----------------|------------------|
| A | V _{CCQ} | A | A | $\overline{\text{ADSP}}$ | A | A | V _{CCQ} |
| B | NC | CE ₂ | A | $\overline{\text{ADSC}}$ | A | A | NC |
| C | NC | A | A | V _{CC} | A | A | NC |
| D | DQc | DQc | V _{SS} | NC | V _{SS} | DQb | DQb |
| E | DQc | DQc | V _{SS} | $\overline{\text{CE}}$ | V _{SS} | DQb | DQb |
| F | V _{CCQ} | DQc | V _{SS} | $\overline{\text{OE}}$ | V _{SS} | DQb | V _{CCQ} |
| G | DQc | DQc | $\overline{\text{BWc}}$ | $\overline{\text{ADV}}$ | $\overline{\text{BWb}}$ | DQb | DQb |
| H | DQc | DQc | V _{SS} | $\overline{\text{GW}}$ | V _{SS} | DQb | DQb |
| J | V _{CCQ} | V _{CC} | NC | V _{CC} | NC | V _{CC} | V _{CCQ} |
| K | DQd | DQd | V _{SS} | CLK | V _{SS} | DQa | DQa |
| L | DQd | DQd | $\overline{\text{BWd}}$ | NC | $\overline{\text{BWa}}$ | DQa | DQa |
| M | V _{CCQ} | DQd | V _{SS} | $\overline{\text{BWE}}$ | V _{SS} | DQa | V _{CCQ} |
| N | DQd | DQd | V _{SS} | A1 | V _{SS} | DQa | DQa |
| P | DQd | DQd | V _{SS} | A0 | V _{SS} | DQa | DQa |
| R | NC | A | MODE | V _{CC} | NC | A | NC |
| T | NC | NC | A | A | A | NC | ZZ |
| U | V _{CCQ} | TMS | TDI | TCK | TDO | NC | V _{CCQ} |

512Kx18

| | 1 | 2 | 3 | 4 | 5 | 6 | 7 |
|----------|------------------|-----------------|-------------------------|--------------------------|-------------------------|-------------------------|------------------|
| A | V _{CCQ} | A | A | $\overline{\text{ADSP}}$ | A | A | V _{CCQ} |
| B | NC | CE ₂ | A | $\overline{\text{ADSC}}$ | A | $\overline{\text{CE2}}$ | NC |
| C | NC | A | A | V _{CC} | A | A | NC |
| D | DQb | NC | V _{SS} | NC | V _{SS} | DQa | NC |
| E | NC | DQb | V _{SS} | $\overline{\text{CE}}$ | V _{SS} | NC | DQa |
| F | V _{CCQ} | NC | V _{SS} | $\overline{\text{OE}}$ | V _{SS} | DQa | V _{CCQ} |
| G | NC | DQb | $\overline{\text{BWb}}$ | $\overline{\text{ADV}}$ | V _{SS} | NC | DQa |
| H | DQb | NC | V _{SS} | $\overline{\text{GW}}$ | V _{SS} | DQa | NC |
| J | V _{CCQ} | V _{CC} | NC | V _{CC} | NC | V _{CC} | V _{CCQ} |
| K | NC | DQb | V _{SS} | CLK | V _{SS} | NC | DQa |
| L | DQb | NC | V _{SS} | NC | $\overline{\text{BWa}}$ | DQa | NC |
| M | V _{CCQ} | DQb | V _{SS} | $\overline{\text{BWE}}$ | V _{SS} | NC | V _{CCQ} |
| N | DQb | NC | V _{SS} | A1 | V _{SS} | DQa | NC |
| P | NC | DQb | V _{SS} | A0 | V _{SS} | NC | DQa |
| R | NC | A | MODE | V _{CC} | NC | A | NC |
| T | NC | A | A | NC | A | A | ZZ |
| U | V _{CCQ} | TMS | TDI | TCK | TDO | NC | V _{CCQ} |



256K X 36 Pin Descriptions

| X36 PBGA Pins | X36 QFP Pins | Name | Type | Description |
|----------------------------------------------------------------------------------|-----------------------------------------------------------------------------------------------------------------------|------------------------------------------------------------------------------|------------------------|--------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 4P 4N 2A, 3A, 5A, 6A, 3B, 5B, 6B, 2C, 3C, 5C, 6C, 2R, 6R, 3T, 4T, 5T | 37 36 35, 34, 33, 32, 100, 99, 82, 81, 44, 45, 46, 47, 48, 49, 50 92 (T Version) 43 (TA Version) | A0 A1 A | Input- Synchronous | Addresses: These inputs are registered and must meet the set-up and hold times around the rising edge of CLK. The burst counter generates internal addresses associated with A0 and A1, during burst cycle and wait cycle. |
| 5L 5G 3G 3L | 93 94 95 96 | \overline{BWA} \overline{BWB} \overline{BWC} \overline{BWD} | Input- Synchronous | Byte Write: A byte write is LOW for a WRITE cycle and HIGH for a READ cycle. \overline{BWA} controls DQa. \overline{BWB} controls DQb. \overline{BWC} controls DQc. \overline{BWD} controls DQd. Data I/O are high impedance if either of these inputs are LOW, conditioned by \overline{BWE} being LOW. |
| 4M | 87 | \overline{BWE} | Input- Synchronous | Write Enable: This active LOW input gates byte write operations and must meet the set-up and hold times around the rising edge of CLK. |
| 4H | 88 | \overline{GW} | Input- Synchronous | Global Write: This active LOW input allows a full 36-bit WRITE to occur independent of the \overline{BWE} and \overline{BWN} lines and must meet the set-up and hold times around the rising edge of CLK. |
| 4K | 89 | CLK | Input- Synchronous | Clock: This signal registers the addresses, data, chip enables, write control, and burst control inputs on its rising edge. All synchronous inputs must meet set-up and hold times around the clock's rising edge. |
| 4E | 98 | \overline{CE} | Input- Synchronous | Chip Enable: This active LOW input is used to enable the device and to gate \overline{ADSP} . |
| 2B | 97 | CE_2 | Input- Synchronous | Chip Enable: This active HIGH input is used to enable the device. |
| - (not available for PBGA) | 92 (for TA Version only) | \overline{CE}_2 | Input- Synchronous | Chip Enable: This active LOW input is used to enable the device. Not available for B and T package versions. |
| 4F | 86 | \overline{OE} | Input | Output Enable: This active LOW asynchronous input enables the data output drivers. |
| 4G | 83 | \overline{ADV} | Input- Synchronous | Address Advance: This active LOW input is used to control the internal burst counter. A HIGH on this pin generates wait cycle (no address advance). |
| 4A | 84 | \overline{ADSP} | Input- Synchronous | Address Status Processor: This active LOW input, along with \overline{CE} being LOW, causes a new external address to be registered and a READ cycle is initiated using the new address. |
| 4B | 85 | \overline{ADSC} | Input- Synchronous | Address Status Controller: This active LOW input causes the device to be deselected or selected along with new external address to be registered. A READ or WRITE cycle is initiated depending upon write control inputs. |
| 3R | 31 | MODE | Input- Static | Mode: This input selects the burst sequence. A LOW on this pin selects Linear Burst. A NC or HIGH on this pin selects Interleaved Burst. |
| 7T | 64 | ZZ | Input- Asynchronous | Snooze: This active HIGH input puts the device in low power consumption standby mode. For normal operation, this input has to be either LOW or NC (No Connect). |

256K X 36 Pin Descriptions (continued)

| X36 PBGA Pins | X36 QFP Pins | Name | Type | Description |
|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------------|--------------------------|------------------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| (a) 6P, 7P, 7N, 6N, 6M, 6L, 7L, 6K, 7K, (b) 7H, 6H, 7G, 6G, 6F, 6E, 7E, 7D, 6D, (c) 2D, 1D, 1E, 2E, 2F, 1G, 2G, 1H, 2H, (d) 1K, 2K, 1L, 2L, 2M, 1N, 2N, 1P, 2P | (a) 51, 52, 53, 56, 57, 58, 59, 62, 63 (b) 68, 69, 72, 73, 74, 75, 78, 79, 80 (c) 1, 2, 3, 6, 7, 8, 9, 12, 13 (d) 18, 19, 22, 23, 24, 25, 28, 29, 30 | DQa DQb DQc DQd | Input/ Output | Data Inputs/Outputs: First Byte is DQa. Second Byte is DQb. Third Byte is DQc. Fourth Byte is DQd. Input data must meet set-up and hold times around the rising edge of CLK. |
| 2U 3U 4U | 38 39 43 for B and T version | TMS TDI TCK | Input | IEEE 1149.1 test inputs. LVTTTL-level inputs. Not available for TA package version. |
| 5U | 42 for B and T version | TDO | Output | IEEE 1149.1 test output. LVTTTL-level output. Not available for TA package version. |
| 4C, 2J, 4J, 6J, 4R | 15, 41, 65, 91 | V _{CC} | Supply | Core power Supply: +3.3V –5% and +10% |
| 3D, 5D, 3E, 5E, 3F, 5F, 3H, 5H, 3K, 5K, 3M, 5M, 3N, 5N, 3P, 5P | 5, 10, 17, 21, 26, 40, 55, 60, 67, 71, 76, 90 | V _{SS} | Ground | Ground: GND. |
| 1A, 7A, 1F, 7F, 1J, 7J, 1M, 7M, 1U, 7U | 4, 11, 20, 27, 54, 61, 70, 77 | V _{CCQ} | I/O Supply | Output Buffer Supply: +2.5V or +3.3V. |
| 1B, 7B, 1C, 7C, 4D, 3J, 5J, 4L, 1R, 5R, 7R, 1T, 2T, 6T, 6U | 14, 16, 66 38, 39, 42 for TA Version | NC | - | No Connect: These signals are not internally connected. User can leave it floating or connect it to V _{CC} or V _{SS} . |

512K X 18 Pin Descriptions

| X18 PBGA Pins | X18 QFP Pins | Name | Type | Description |
|-----------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------------------------------------------|--------------------------------------|-----------------------|-------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 4P 4N 2A, 3A, 5A, 6A, 3B, 5B, 6B, 2C, 3C, 5C, 6C, 2R, 6R, 2T, 3T, 5T, 6T | 37 36 35, 34, 33, 32, 100, 99, 82, 81, 80, 48, 47, 46, 45, 44, 49, 50 92 (T Version) 43 (TA Version) | A0 A1 A | Input- Synchronous | Addresses: These inputs are registered and must meet the set up and hold times around the rising edge of CLK. The burst counter generates internal addresses associated with A0 and A1, during burst cycle and wait cycle. |
| 5L 3G | 93 94 | \overline{BWA} \overline{BWb} | Input- Synchronous | Byte Write Enables: A byte write enable is <u>LOW</u> for a <u>WRITE</u> cycle and <u>HIGH</u> for a <u>READ</u> cycle. \overline{BWA} controls DQa. \overline{BWb} controls DQb. Data I/O are high impedance if either of these inputs are LOW, conditioned by \overline{BWE} being LOW. |
| 4M | 87 | \overline{BWE} | Input- Synchronous | Write Enable: This active LOW input gates byte write operations and must meet the set-up and hold times around the rising edge of CLK. |
| 4H | 88 | \overline{GW} | Input- Synchronous | Global Write: This active LOW input allows a full 18-bit <u>WRITE</u> to occur independent of the \overline{BWE} and \overline{WEN} lines and must meet the set-up and hold times around the rising edge of CLK. |
| 4K | 89 | CLK | Input- Synchronous | Clock: This signal registers the addresses, data, chip enables, write control and burst control inputs on its rising edge. All synchronous inputs must meet set-up and hold times around the clock's rising edge. |
| 4E | 98 | \overline{CE} | Input- Synchronous | Chip Enable: This active LOW input is used to enable the device and to gate ADSP. |

512K X 18 Pin Descriptions (continued)

| X18 PBGA Pins | X18 QFP Pins | Name | Type | Description |
|--------------------------------------------------------------------------------------------------------------------------------|----------------------------------------------------------------------------------------------------------|-------------------|--------------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| 2B | 97 | CE2 | Input-Synchronous | Chip Enable: This active HIGH input is used to enable the device. |
| - (not available for PBGA) | 92 (for TA Version only) | $\overline{CE2}$ | Input-Synchronous | Chip Enable: This active LOW input is used to enable the device. Not available for B and T package versions. |
| 4F | 86 | \overline{OE} | Input | Output Enable: This active LOW asynchronous input enables the data output drivers. |
| 4G | 83 | \overline{ADV} | Input-Synchronous | Address Advance: This active LOW input is used to control the internal burst counter. A HIGH on this pin generates wait cycle (no address advance). |
| 4A | 84 | \overline{ADSP} | Input-Synchronous | Address Status Processor: This active LOW input, along with \overline{CE} being LOW, causes a new external address to be registered and a READ cycle is initiated using the new address. |
| 4B | 85 | \overline{ADSC} | Input-Synchronous | Address Status Controller: This active LOW input causes device to be deselected or selected along with new external address to be registered. A READ or WRITE cycle is initiated depending upon write control inputs. |
| 3R | 31 | MODE | Input-Static | Mode: This input selects the burst sequence. A LOW on this pin selects Linear Burst. An NC or HIGH on this pin selects Interleaved Burst. |
| 7T | 64 | ZZ | Input-Asynchronous | Snooze: This active HIGH input puts the device in low power consumption standby mode. For normal operation, this input has to be either LOW or NC (No Connect). |
| (a) 6D, 7E, 6F, 7G, 6H, 7K, 6L, 6N, 7P (b) 1D, 2E, 2G, 1H, 2K, 1L, 2M, 1N, 2P | (a) 58, 59, 62, 63, 68, 69, 72, 73, 74 (b) 8, 9, 12, 13, 18, 19, 22, 23, 24 | DQa DQb | Input/Output | Data Inputs/Outputs: Low Byte is DQa. High Byte is DQb. Input data must meet set up and hold times around the rising edge of CLK. |
| 2U 3U 4U | 38 39 43 for B and T version | TMS TDI TCK | Input | IEEE 1149.1 test inputs. LVTTTL-level inputs. Not available for TA package version. |
| 5U | 42 for B and T version | TDO | Output | IEEE 1149.1 test output. LVTTTL-level output. Not available for TA package version. |
| 4C, 2J, 4J, 6J, 4R | 15, 41, 65, 91 | V _{CC} | Supply | Core power Supply: +3.3V -5% and +10% |
| 3D, 5D, 3E, 5E, 3F, 5F, 5G, 3H, 5H, 3K, 5K, 3L, 3M, 5M, 3N, 5N, 3P, 5P | 5, 10, 17, 21, 26, 40, 55, 60, 67, 71, 76, 90 | V _{SS} | Ground | Ground: GND. |
| 1A, 7A, 1F, 7F, 1J, 7J, 1M, 7M, 1U, 7U | 4, 11, 20, 27, 54, 61, 70, 77 | V _{CCQ} | I/O Supply | Output Buffer Supply: +2.5V or +3.3V. |
| 1B, 7B, 1C, 7C, 2D, 4D, 7D, 1E, 6E, 2F, 1G, 6G, 2H, 7H, 3J, 5J, 1K, 6K, 2L, 4L, 7L, 6M, 2N, 7N, 1P, 6P, 1R, 5R, 7R, 1T, 4T, 6U | 1-3, 6, 7, 14, 16, 25, 28-30, 51-53, 56, 57, 66, 75, 78, 79, 80, 95, 96 38, 39, 42 for TA Version | NC | - | No Connect: These signals are not internally connected. User can leave it floating or connect it to V _{CC} or V _{SS} . |



Burst Address Table (MODE = NC/V_{CC})

| First Address (external) | Second Address (internal) | Third Address (internal) | Fourth Address (internal) |
|--------------------------|---------------------------|--------------------------|---------------------------|
| A...A00 | A...A01 | A...A10 | A...A11 |
| A...A01 | A...A00 | A...A11 | A...A10 |
| A...A10 | A...A11 | A...A00 | A...A01 |
| A...A11 | A...A10 | A...A01 | A...A00 |

Burst Address Table (MODE = GND)

| First Address (external) | Second Address (internal) | Third Address (internal) | Fourth Address (internal) |
|--------------------------|---------------------------|--------------------------|---------------------------|
| A...A00 | A...A01 | A...A10 | A...A11 |
| A...A01 | A...A10 | A...A11 | A...A00 |
| A...A10 | A...A11 | A...A00 | A...A01 |
| A...A11 | A...A00 | A...A01 | A...A10 |

Truth Table^[3, 4, 5, 6, 7, 8, 9]

| Operation | Address Used | CE | CE2 | CE2 | ADSP | ADSC | ADV | WRITE | OE | CLK | DQ |
|------------------------------|--------------|----|-----|-----|------|------|-----|-------|----|-----|--------|
| Deselected Cycle, Power Down | None | H | X | X | X | L | X | X | X | L-H | High-Z |
| Deselected Cycle, Power Down | None | L | X | L | L | X | X | X | X | L-H | High-Z |
| Deselected Cycle, Power Down | None | L | H | X | L | X | X | X | X | L-H | High-Z |
| Deselected Cycle, Power Down | None | L | X | L | H | L | X | X | X | L-H | High-Z |
| Deselected Cycle, Power Down | None | L | H | X | H | L | X | X | X | L-H | High-Z |
| READ Cycle, Begin Burst | External | L | L | H | L | X | X | X | L | L-H | Q |
| READ Cycle, Begin Burst | External | L | L | H | L | X | X | X | H | L-H | High-Z |
| WRITE Cycle, Begin Burst | External | L | L | H | H | L | X | L | X | L-H | D |
| READ Cycle, Begin Burst | External | L | L | H | H | L | X | H | L | L-H | Q |
| READ Cycle, Begin Burst | External | L | L | H | H | L | X | H | H | L-H | High-Z |
| READ Cycle, Continue Burst | Next | X | X | X | H | H | L | H | L | L-H | Q |
| READ Cycle, Continue Burst | Next | X | X | X | H | H | L | H | H | L-H | High-Z |
| READ Cycle, Continue Burst | Next | H | X | X | X | H | L | H | L | L-H | Q |
| READ Cycle, Continue Burst | Next | H | X | X | X | H | L | H | H | L-H | High-Z |
| WRITE Cycle, Continue Burst | Next | X | X | X | H | H | L | L | X | L-H | D |
| WRITE Cycle, Continue Burst | Next | H | X | X | X | H | L | L | X | L-H | D |
| READ Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | L | L-H | Q |
| READ Cycle, Suspend Burst | Current | X | X | X | H | H | H | H | H | L-H | High-Z |
| READ Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | L | L-H | Q |
| READ Cycle, Suspend Burst | Current | H | X | X | X | H | H | H | H | L-H | High-Z |
| WRITE Cycle, Suspend Burst | Current | X | X | X | H | H | H | L | X | L-H | D |
| WRITE Cycle, Suspend Burst | Current | H | X | X | X | H | H | L | X | L-H | D |

Notes:

- X = "Don't Care." H = logic HIGH. L = logic LOW.
For X36 product, WRITE = L means $\overline{BWE} + \overline{BWA} \cdot \overline{BWB} \cdot \overline{BWC} \cdot \overline{BWD} \cdot \overline{GW}$ equals LOW. WRITE = H means $\overline{BWE} + \overline{BWA} \cdot \overline{BWB} \cdot \overline{BWC} \cdot \overline{BWD} \cdot \overline{GW}$ equals HIGH.
For X18 product, WRITE = L means $\overline{BWE} + \overline{BWA} \cdot \overline{BWB} \cdot \overline{GW}$ equals LOW. WRITE = H means $\overline{BWE} + \overline{BWA} \cdot \overline{BWB} \cdot \overline{GW}$ equals HIGH.
- BWA enables write to DQa. BWb enables write to DQb. BWC enables write to DQc. BWD enables write to DQd.
- All inputs except OE must meet set up and hold times around the rising edge (LOW to HIGH) of CLK.
- Suspending burst generates wait cycle.
- For a write operation following a read operation, OE must be HIGH before the input data required set-up time plus High-Z time for OE and staying HIGH throughout the input data hold time.
- This device contains circuitry that will ensure the outputs will be in High-Z during power-up.
- ADSP LOW along with chip being selected always initiates a READ cycle at the L-H edge of CLK. A WRITE cycle can be performed by setting WRITE LOW for the CLK L-H edge of the subsequent wait cycle. Refer to WRITE timing diagram for clarification.



Partial Truth Table for READ/WRITE^[10]

| Function | \overline{GW} | \overline{BWE} | \overline{BWA} | \overline{BWB} | \overline{BWC} | \overline{BWD} |
|-----------------|-----------------|------------------|------------------|------------------|------------------|------------------|
| READ | H | H | X | X | X | X |
| READ | H | L | H | H | H | H |
| WRITE one byte | H | L | L | H | H | H |
| WRITE all bytes | H | L | L | L | L | L |
| WRITE all bytes | L | X | X | X | X | X |

IEEE 1149.1 Serial Boundary Scan (JTAG)

Overview

This device incorporates a serial boundary scan access port (TAP). This port is designed to operate in a manner consistent with IEEE Standard 1149.1-1990 (commonly referred to as JTAG), but does not implement all of the functions required for IEEE 1149.1 compliance. Certain functions have been modified or eliminated because their implementation places extra delays in the critical speed path of the device. Nevertheless, the device supports the standard TAP controller architecture (the TAP controller is the state machine that controls the TAPs operation) and can be expected to function in a manner that does not conflict with the operation of devices with IEEE Standard 1149.1 compliant TAPs. The TAP operates using LVTTTL/LVCMOS logic level signaling.

Disabling the JTAG Feature

It is possible to use this device without using the JTAG feature. To disable the TAP controller without interfering with normal operation of the device, TCK should be tied LOW (V_{SS}) to prevent clocking the device. TDI and TMS are internally pulled up and may be unconnected. They may alternately be pulled up to V_{CC} through a resistor. TDO should be left unconnected. Upon power-up the device will come up in a reset state which will not interfere with the operation of the device.

Test Access Port (TAP)

TCK - Test Clock (INPUT)

Clocks all TAP events. All inputs are captured on the rising edge of TCK and all outputs propagate from the falling edge of TCK.

TMS - Test Mode Select (INPUT)

The TMS input is sampled on the rising edge of TCK. This is the command input for the TAP controller state machine. It is allowable to leave this pin unconnected if the TAP is not used. The pin is pulled up internally, resulting in a logic HIGH level.

TDI - Test Data In (INPUT)

The TDI input is sampled on the rising edge of TCK. This is the input side of the serial registers placed between TDI and TDO. The register placed between TDI and TDO is determined by the state of the TAP controller state machine and the instruction that is currently loaded in the TAP instruction register (refer to Figure 1, TAP Controller State Diagram). It is allowable to leave this pin unconnected if it is not used in an application. The pin is pulled up internally, resulting in a logic HIGH level. TDI is connected to the Most Significant Bit (MSB) of any register. (See Figure 2.)

Note:

10. For the X18 product, there are only \overline{BWA} and \overline{BWB} .

TDO - Test Data Out (OUTPUT)

The TDO output pin is used to serially clock data-out from the registers. The output that is active depending on the state of the TAP state machine (refer to Figure 1, TAP Controller State Diagram). Output changes in response to the falling edge of TCK. This is the output side of the serial registers placed between TDI and TDO. TDO is connected to the Least Significant Bit (LSB) of any register. (See Figure 2.)

Performing a TAP Reset

The TAP circuitry does not have a reset pin (\overline{TRST} , which is optional in the IEEE 1149.1 specification). A RESET can be performed for the TAP controller by forcing TMS HIGH (V_{CC}) for five rising edges of TCK and pre-loads the instruction register with the IDCODE command. This type of reset does not affect the operation of the system logic. The reset affects test logic only.

At power-up, the TAP is reset internally to ensure that TDO is in a High-Z state.

Test Access Port (TAP) Registers

Overview

The various TAP registers are selected (one at a time) via the sequences of ones and zeros input to the TMS pin as the TCK is strobed. Each of the TAPs registers are serial shift registers that capture serial input data on the rising edge of TCK and push serial data out on subsequent falling edge of TCK. When a register is selected, it is connected between the TDI and TDO pins.

Instruction Register

The instruction register holds the instructions that are executed by the TAP controller when it is moved into the run test/idle or the various data register states. The instructions are three bits long. The register can be loaded when it is placed between the TDI and TDO pins. The parallel outputs of the instruction register are automatically preloaded with the IDCODE instruction upon power-up or whenever the controller is placed in the test-logic reset state. When the TAP controller is in the Capture-IR state, the two least significant bits of the serial instruction register are loaded with a binary "01" pattern to allow for fault isolation of the board-level serial test data path.

Bypass Register

The bypass register is a single-bit register that can be placed between TDI and TDO. It allows serial test data to be passed through the device TAP to another device in the scan chain with minimum delay. The bypass register is set LOW (V_{SS}) when the BYPASS instruction is executed.

Boundary Scan Register

The Boundary Scan register is connected to all the input and bidirectional I/O pins (not counting the TAP pins) on the device. This also includes a number of NC pins that are reserved for future needs. There are a total of 70 bits for the x36 device and 51 bits for the x18 device. The boundary scan register, under the control of the TAP controller, is loaded with the contents of the device I/O ring when the controller is in Capture-DR state and then is placed between the TDI and TDO pins when the controller is moved to Shift-DR state. The EXTEST, SAMPLE/PRELOAD and SAMPLE-Z instructions can be used to capture the contents of the I/O ring.

The Boundary Scan Order table describes the order in which the bits are connected. The first column defines the bit's position in the boundary scan register. The MSB of the register is connected to TDI, and LSB is connected to TDO. The second column is the signal name, the third column is the TQFP pin number, and the fourth column is the BGA bump number.

Identification (ID) Register

The ID Register is a 32-bit register that is loaded with a device and vendor specific 32-bit code when the controller is put in Capture-DR state with the IDCODE command loaded in the instruction register. The register is then placed between the TDI and TDO pins when the controller is moved into Shift-DR state. Bit 0 in the register is the LSB and the first to reach TDO when shifting begins. The code is loaded from a 32-bit on-chip ROM. It describes various attributes of the device as described in the Identification Register Definitions table.

TAP Controller Instruction Set

Overview

There are two classes of instructions defined in the IEEE Standard 1149.1-1990; the standard (public) instructions and device specific (private) instructions. Some public instructions are mandatory for IEEE 1149.1 compliance. Optional public instructions must be implemented in prescribed ways.

Although the TAP controller in this device follows the IEEE 1149.1 conventions, it is not IEEE 1149.1 compliant because some of the mandatory instructions are not fully implemented. The TAP on this device may be used to monitor all input and I/O pads, but can not be used to load address, data, or control signals into the device or to preload the I/O buffers. In other words, the device will not perform IEEE 1149.1 EXTEST, INTEST, or the preload portion of the SAMPLE/PRELOAD command.

When the TAP controller is placed in Capture-IR state, the two least significant bits of the instruction register are loaded with 01. When the controller is moved to the Shift-IR state the instruction is serially loaded through the TDI input (while the previous contents are shifted out at TDO). For all instructions, the TAP executes newly loaded instructions only when the controller is moved to Update-IR state. The TAP instruction sets for this device are listed in the following tables.

EXTEST

EXTEST is an IEEE 1149.1 mandatory public instruction. It is to be executed whenever the instruction register is loaded with all 0s. EXTEST is not implemented in this device.

The TAP controller does not recognize an all-0 instruction. When an EXTEST instruction is loaded into the instruction register, the device responds as if a SAMPLE/PRELOAD instruction has been loaded. There is one difference between two instructions. Unlike SAMPLE/PRELOAD instruction, EXTEST places the device outputs in a High-Z state.

IDCODE

The IDCODE instruction causes a vendor-specific, 32-bit code to be loaded into the ID register when the controller is in Capture-DR mode and places the ID register between the TDI and TDO pins in Shift-DR mode. The IDCODE instruction is the default instruction loaded in the instruction upon power-up and at any time the TAP controller is placed in the test-logic reset state.

SAMPLE-Z

If the High-Z instruction is loaded in the instruction register, all output pins are forced to a High-Z state and the boundary scan register is connected between TDI and TDO pins when the TAP controller is in a Shift-DR state.

SAMPLE/PRELOAD

SAMPLE/PRELOAD is an IEEE 1149.1 mandatory instruction. The PRELOAD portion of the command is not implemented in this device, so the device TAP controller is not fully IEEE 1149.1-compliant.

When the SAMPLE/PRELOAD instruction is loaded in the instruction register and the TAP controller is in the Capture-DR state, a snap shot of the data in the device's input and I/O buffers is loaded into the boundary scan register. Because the device system clock(s) are independent from the TAP clock (TCK), it is possible for the TAP to attempt to capture the input and I/O ring contents while the buffers are in transition (i.e., in a metastable state). Although allowing the TAP to sample metastable inputs will not harm the device, repeatable results can not be expected. To guarantee that the boundary scan register will capture the correct value of a signal, the device input signals must be stabilized long enough to meet the TAP controller's capture set up plus hold time (t_{CS} plus t_{CH}). The device clock input(s) need not be paused for any other TAP operation except capturing the input and I/O ring contents into the boundary scan register.

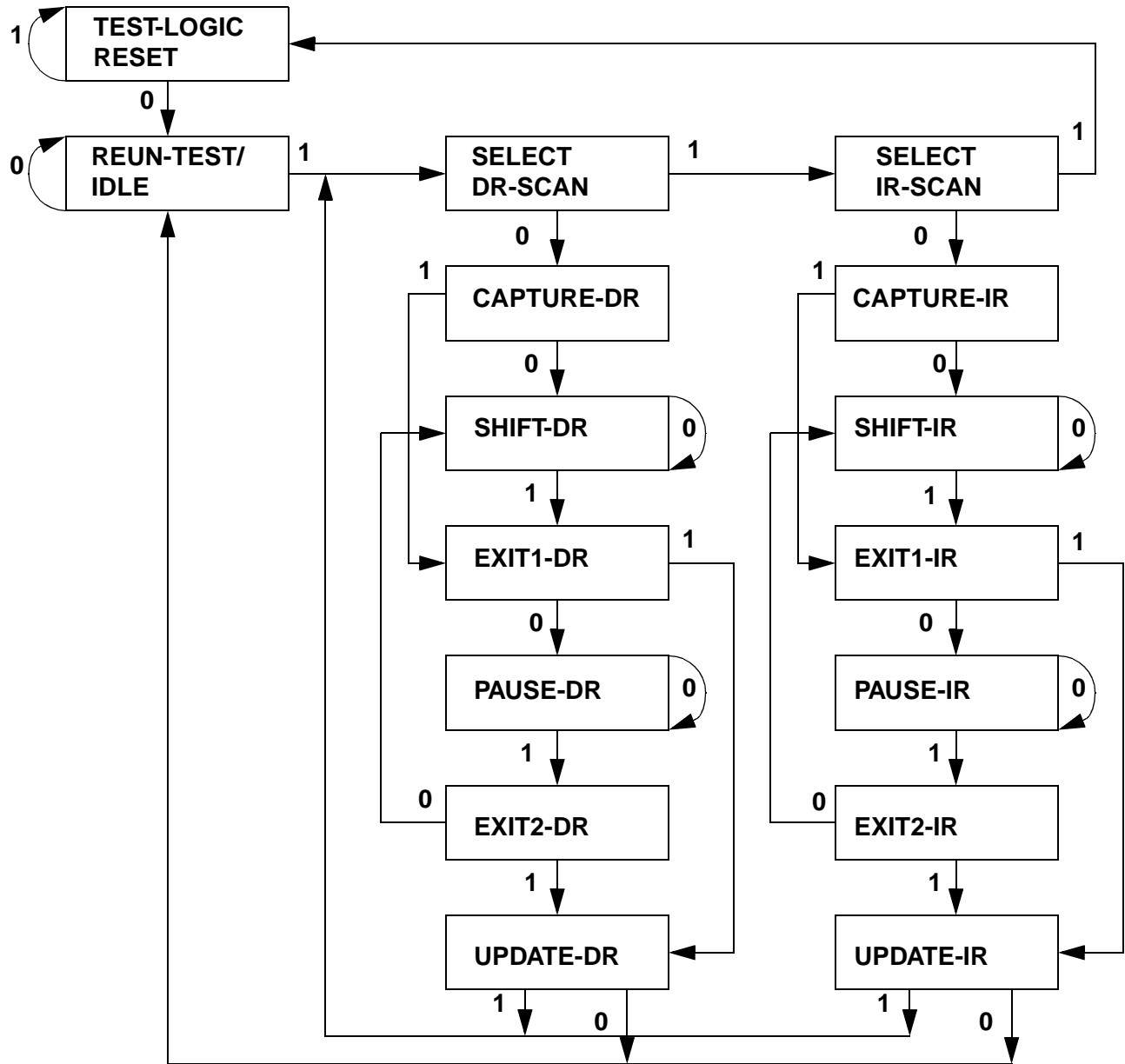
Moving the controller to Shift-DR state then places the boundary scan register between the TDI and TDO pins. Because the PRELOAD portion of the command is not implemented in this device, moving the controller to the Update-DR state with the SAMPLE/PRELOAD instruction loaded in the instruction register has the same effect as the Pause-DR command.

BYPASS

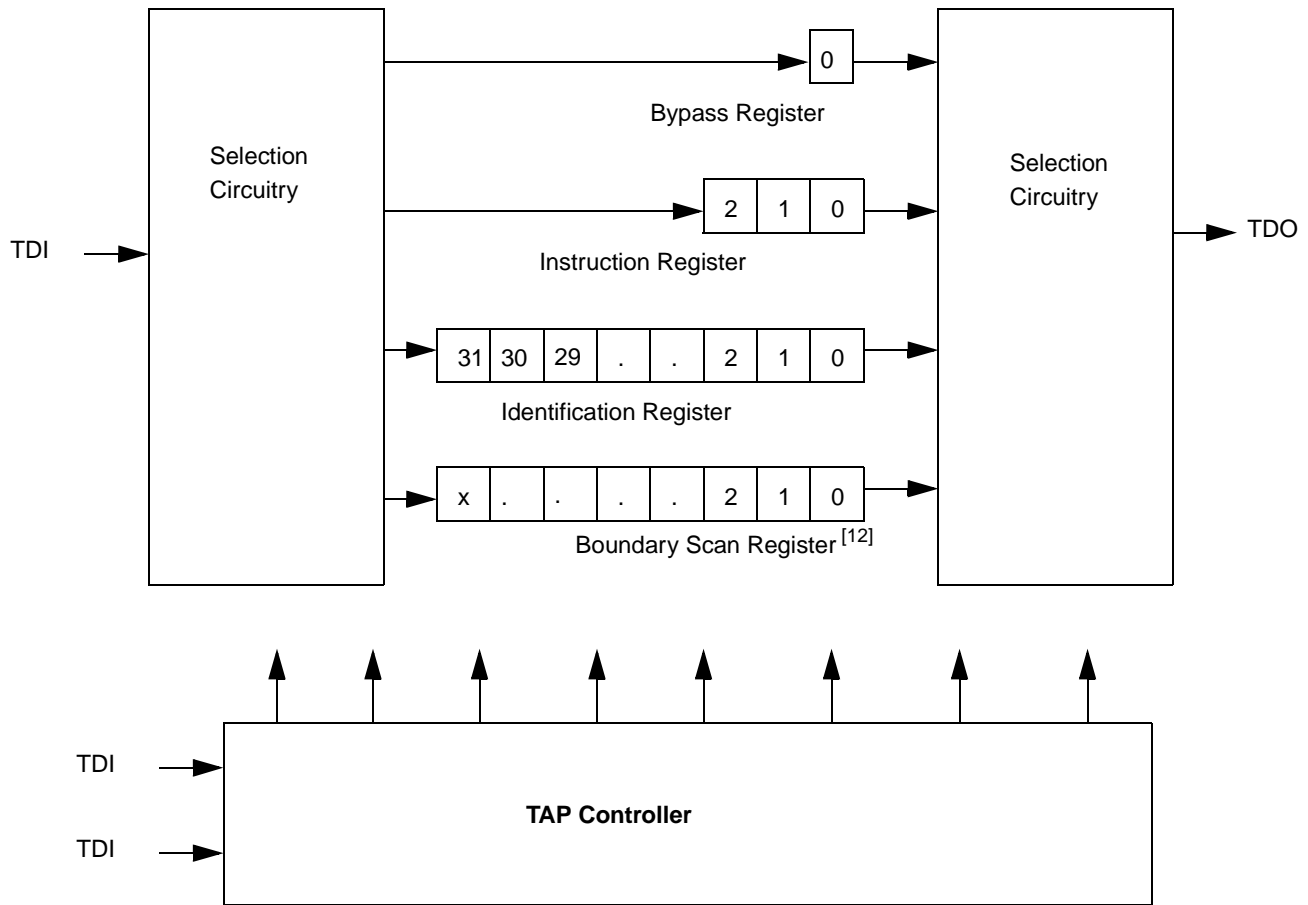
When the BYPASS instruction is loaded in the instruction register and the TAP controller is in the Shift-DR state, the bypass register is placed between TDI and TDO. This allows the board level scan path to be shortened to facilitate testing of other devices in the scan path.

Reserved

Do not use these instructions. They are reserved for future use.


Figure 1. TAP Controller State Diagram^[11]
Note:

11. The 0/1 next to each state represents the value at TMS at the rising edge of TCK.


Figure 2. TAP Controller Block Diagram
TAP Electrical Characteristics (20°C < T_j < 110°C; V_{CC} = 3.3V –0.2V and +0.3V unless otherwise noted)

| Parameter | Description | Test Conditions | Min. | Max. | Unit |
|------------------|--------------------------------------------------|-------------------------------------------------------------|-----------------------|-----------------------|------|
| V _{IH} | Input High (Logic 1) Voltage ^[13, 14] | | 2.0 | V _{CC} + 0.3 | V |
| V _{IL} | Input Low (Logic 0) Voltage ^[13, 14] | | -0.3 | 0.8 | V |
| I _{L1} | Input Leakage Current | 0V ≤ V _{IN} ≤ V _{CC} | -5.0 | 5.0 | μA |
| I _{L1} | TMS and TDI Input Leakage Current | 0V ≤ V _{IN} ≤ V _{CC} | -30 | 30 | μA |
| I _{LO} | Output Leakage Current | Output disabled, 0V ≤ V _{IN} ≤ V _{CCQ} | -5.0 | 5.0 | μA |
| V _{OLC} | LVC MOS Output Low Voltage ^[13, 15] | I _{OLC} = 100 μA | | 0.2 | V |
| V _{OHC} | LVC MOS Output High Voltage ^[13, 15] | I _{OHC} = 100 μA | V _{CC} - 0.2 | | V |
| V _{OLT} | LVTTTL Output Low Voltage ^[13] | I _{OLT} = 8.0 mA | | 0.4 | V |
| V _{OHT} | LVTTTL Output High Voltage ^[13] | I _{OHT} = 8.0 mA | 2.4 | | V |

Notes:

12. X = 69 for the x36 configuration;
X = 50 for the x18 configuration.
13. All Voltage referenced to V_{SS} (GND).
14. Overshoot: V_{IH}(AC) ≤ V_{CC} + 1.5V for t_s ≤ t_{KHKH}/2, Undershoot: V_{IL}(AC) ≤ -0.5V for t_s ≤ t_{KHKH}/2, Power-up: V_{IH} ≤ 3.6V and V_{CC} ≤ 3.135V and V_{CCQ} ≤ 1.4V for t_s ≤ 200 ms. During normal operation, V_{CCQ} must not exceed V_{CC}. Control input signals (such as R/W, ADV/LD, etc.) may not have pulse widths less than t_{KHKL} (min.).
15. This parameter is sampled.



PRELIMINARY

**CY7C1360A/GVT71256D36
CY7C1362A/GVT71512D18**

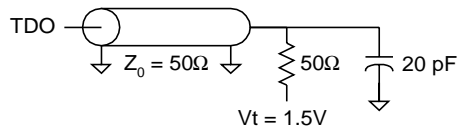
TAP AC Switching Characteristics Over the Operating Range^[16, 17]

| Parameter | Description | Min. | Max | Unit |
|---------------------|-------------------------|------|-----|------|
| Clock | | | | |
| t_{THTH} | Clock Cycle Time | 20 | | ns |
| f_{TF} | Clock Frequency | | 50 | MHz |
| t_{HTL} | Clock HIGH Time | 8 | | ns |
| t_{LTH} | Clock LOW Time | 8 | | ns |
| Output Times | | | | |
| t_{LQX} | TCK LOW to TDO Unknown | 0 | | ns |
| t_{LQV} | TCK LOW to TDO Valid | | 10 | ns |
| t_{DVTH} | TDI Valid to TCK HIGH | 5 | | ns |
| t_{HDX} | TCK HIGH to TDI Invalid | 5 | | ns |
| Set-up Times | | | | |
| t_{MVTH} | TMS Set-up | 5 | | ns |
| t_{CS} | Capture Set-up | 5 | | ns |
| Hold Times | | | | |
| t_{THMX} | TMS Hold | 5 | | ns |
| t_{CH} | Capture Hold | 5 | | ns |

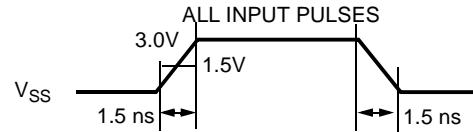
Notes:

- 16. t_{CS} and t_{CH} refer to the set-up and hold time requirements of latching data from the boundary scan register.
- 17. Test conditions are specified using the load in TAP AC test conditions.

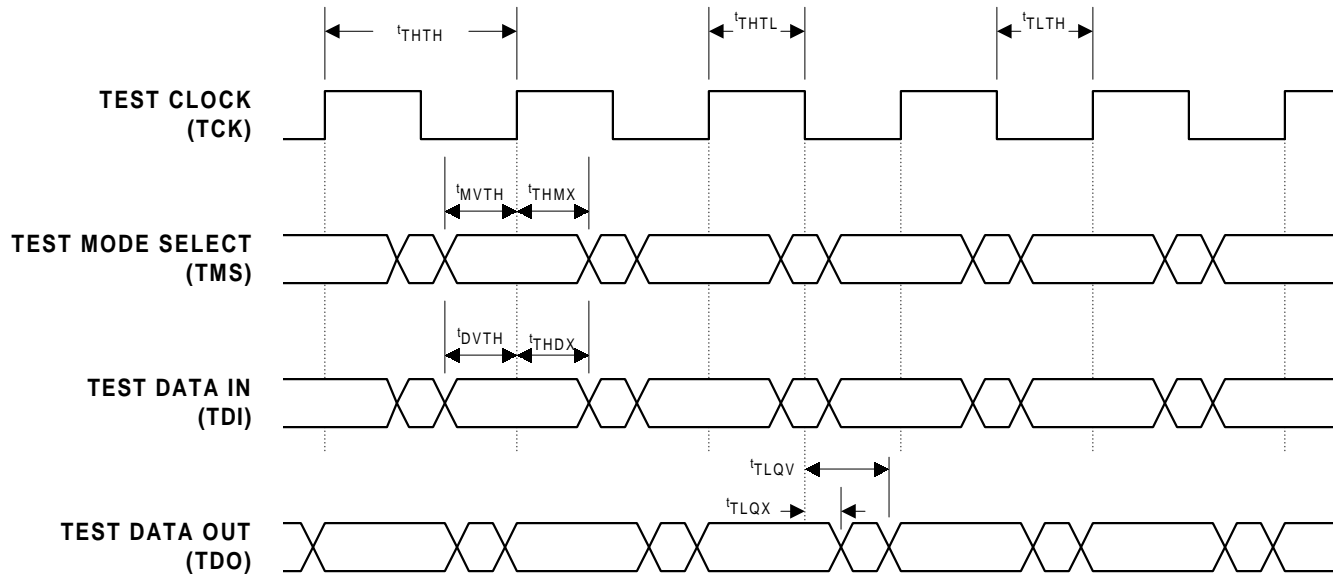
TAP Timing and Test Conditions



(a)



(b)





Identification Register Definitions

| Instruction Field | 256K x 36 | 512K x 18 | Description |
|------------------------------------|-------------|-------------|------------------------------------------------|
| REVISION NUMBER (31:28) | XXXX | XXXX | Reserved for revision number. |
| DEVICE DEPTH (27:23) | 00110 | 00111 | Defines depth of 256K or 512K words. |
| DEVICE WIDTH (22:18) | 00100 | 00011 | Defines width of x36 or x18 bits. |
| RESERVED (17:12) | XXXXXX | XXXXXX | Reserved for future use. |
| CYPRESS JEDEC ID CODE (11:1) | 00011100100 | 00011100100 | Allows unique identification of DEVICE vendor. |
| ID Register Presence Indicator (0) | 1 | 1 | Indicates the presence of an ID register. |

Scan Register Sizes

| Register Name | Bit Size (x36) | Bit Size (x18) |
|---------------|----------------|----------------|
| Instruction | 3 | 3 |
| Bypass | 1 | 1 |
| ID | 32 | 32 |
| Boundary Scan | 70 | 51 |

Instruction Codes

| Instruction | Code | Description |
|----------------|------|------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|
| EXTEST | 000 | Captures I/O ring contents. Places the boundary scan register between TDI and TDO. Forces all device outputs to High-Z state. This instruction is not IEEE 1149.1-compliant. |
| IDCODE | 001 | Preloads ID register with vendor ID code and places it between TDI and TDO. This instruction does not affect device operations. |
| SAMPLE-Z | 010 | Captures I/O ring contents. Places the boundary scan register between TDI and TDO. Forces all device outputs to High-Z state. |
| RESERVED | 011 | Do not use these instructions; they are reserved for future use. |
| SAMPLE/PRELOAD | 100 | Captures I/O ring contents. Places the boundary scan register between TDI and TDO. This instruction does not affect device operations. This instruction does not implement IEEE 1149.1 PRELOAD function and is therefore not 1149.1-compliant. |
| RESERVED | 101 | Do not use these instructions; they are reserved for future use. |
| RESERVED | 110 | Do not use these instructions; they are reserved for future use. |
| BYPASS | 111 | Places the bypass register between TDI and TDO. This instruction does not affect device operations. |



Boundary Scan Order (256K x 36)

| Bit# | Signal Name | TQFP | Bump ID |
|------|-------------------|------|---------|
| 1 | A | 44 | 2R |
| 2 | A | 45 | 3T |
| 3 | A | 46 | 4T |
| 4 | A | 47 | 5T |
| 5 | A | 48 | 6R |
| 6 | A | 49 | 3B |
| 7 | A | 50 | 5B |
| 8 | DQa | 51 | 6P |
| 9 | DQa | 52 | 7N |
| 10 | DQa | 53 | 6M |
| 11 | DQa | 56 | 7L |
| 12 | DQa | 57 | 6K |
| 13 | DQa | 58 | 7P |
| 14 | DQa | 59 | 6N |
| 15 | DQa | 62 | 6L |
| 16 | DQa | 63 | 7K |
| 17 | ZZ | 64 | 7T |
| 18 | DQb | 68 | 6H |
| 19 | DQb | 69 | 7G |
| 20 | DQb | 72 | 6F |
| 21 | DQb | 73 | 7E |
| 22 | DQb | 74 | 6D |
| 23 | DQb | 75 | 7H |
| 24 | DQb | 78 | 6G |
| 25 | DQb | 79 | 6E |
| 26 | DQb | 80 | 7D |
| 27 | A | 81 | 6A |
| 28 | A | 82 | 5A |
| 29 | \overline{ADV} | 83 | 4G |
| 30 | \overline{ADSP} | 84 | 4A |
| 31 | \overline{ADSC} | 85 | 4B |
| 32 | \overline{OE} | 86 | 4F |
| 33 | \overline{BWE} | 87 | 4M |
| 34 | \overline{GW} | 88 | 4H |
| 35 | CLK | 89 | 4K |

Boundary Scan Order (256K x 36) (continued)

| Bit# | Signal Name | TQFP | Bump ID |
|------|------------------|------|---------|
| 36 | A | 92 | 6B |
| 37 | \overline{BWA} | 93 | 5L |
| 38 | \overline{BWb} | 94 | 5G |
| 39 | \overline{BWc} | 95 | 3G |
| 40 | \overline{BWd} | 96 | 3L |
| 41 | CE ₂ | 97 | 2B |
| 42 | \overline{CE} | 98 | 4E |
| 43 | A | 99 | 3A |
| 44 | A | 100 | 2A |
| 45 | DQc | 1 | 2D |
| 46 | DQc | 2 | 1E |
| 47 | DQc | 3 | 2F |
| 48 | DQc | 6 | 1G |
| 49 | DQc | 7 | 2H |
| 50 | DQc | 8 | 1D |
| 51 | DQc | 9 | 2E |
| 52 | DQc | 12 | 2G |
| 53 | DQc | 13 | 1H |
| 54 | NC | 14 | 5R |
| 55 | DQd | 18 | 2K |
| 56 | DQd | 19 | 1L |
| 57 | DQd | 22 | 2M |
| 58 | DQd | 23 | 1N |
| 59 | DQd | 24 | 2P |
| 60 | DQd | 25 | 1K |
| 61 | DQd | 28 | 2L |
| 62 | DQd | 29 | 2N |
| 63 | DQd | 30 | 1P |
| 64 | MODE | 31 | 3R |
| 65 | A | 32 | 2C |
| 66 | A | 33 | 3C |
| 67 | A | 34 | 5C |
| 68 | A | 35 | 6C |
| 69 | A1 | 36 | 4N |
| 70 | A0 | 37 | 4P |



Boundary Scan Order (512K x 18)

| Bit# | Signal Name | TQFP | Bump ID |
|------|-------------------|------|---------|
| 1 | A | 44 | 2R |
| 2 | A | 45 | 2T |
| 3 | A | 46 | 3T |
| 4 | A | 47 | 5T |
| 5 | A | 48 | 6R |
| 6 | A | 49 | 3B |
| 7 | A | 50 | 5B |
| 8 | DQa | 58 | 7P |
| 9 | DQa | 59 | 6N |
| 10 | DQa | 62 | 6L |
| 11 | DQa | 63 | 7K |
| 12 | ZZ | 64 | 7T |
| 13 | DQa | 68 | 6H |
| 14 | DQa | 69 | 7G |
| 15 | DQa | 72 | 6F |
| 16 | DQa | 73 | 7E |
| 17 | DQa | 74 | 6D |
| 18 | A | 80 | 6T |
| 19 | A | 81 | 6A |
| 20 | A | 82 | 5A |
| 21 | \overline{ADV} | 83 | 4G |
| 22 | \overline{ADSP} | 84 | 4A |
| 23 | \overline{ADSC} | 85 | 4B |
| 24 | \overline{OE} | 86 | 4F |
| 25 | \overline{BWE} | 87 | 4M |
| 26 | \overline{GW} | 88 | 4H |

Boundary Scan Order (512K x 18) (continued)

| Bit# | Signal Name | TQFP | Bump ID |
|------|------------------|------|---------|
| 27 | CLK | 89 | 4K |
| 28 | A | 92 | 6B |
| 29 | \overline{BWA} | 93 | 5L |
| 30 | \overline{BWb} | 94 | 3G |
| 31 | CE ₂ | 97 | 2B |
| 32 | \overline{CE} | 98 | 4E |
| 33 | A | 99 | 3A |
| 34 | A | 100 | 2A |
| 35 | DQb | 8 | 1D |
| 36 | DQb | 9 | 2E |
| 37 | DQb | 12 | 2G |
| 38 | DQb | 13 | 1H |
| 39 | NC | 14 | 5R |
| 40 | DQb | 18 | 2K |
| 41 | DQb | 19 | 1L |
| 42 | DQb | 22 | 2M |
| 43 | DQb | 23 | 1N |
| 44 | DQb | 24 | 2P |
| 45 | MODE | 31 | 3R |
| 46 | A | 32 | 2C |
| 47 | A | 33 | 3C |
| 48 | A | 34 | 5C |
| 49 | A | 35 | 6C |
| 50 | A1 | 36 | 4N |
| 51 | A0 | 37 | 4P |



Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

- Voltage on V_{CC} Supply Relative to V_{SS} -0.5V to +4.6V
- V_{IN} -0.5V to V_{CC}+0.5V
- Storage Temperature (plastic) -55°C to +150°
- Junction Temperature +150°

- Power Dissipation 1.0W
- Short Circuit Output Current..... 50 mA

Operating Range

| Range | Ambient Temperature ^[18] | V _{CC} |
|-------|-------------------------------------|-----------------|
| Com'l | 0°C to +70°C | 3.3V -5% / +10% |

Electrical Characteristics Over the Operating Range

| Parameter | Description | Test Conditions | Min. | Max. | Unit |
|------------------|---------------------------------------------------|----------------------------------------------------------------|-------|----------------------|------|
| V _{IHD} | Input High (Logic 1) Voltage ^[13, 19] | Data Inputs (DQx) | 2.0 | V _{CC} +0.3 | V |
| V _{IH} | | All Other Inputs | 2.0 | 4.6 | V |
| V _{IL} | Input Low (Logic 0) Voltage ^[13, 19] | | -0.5 | 0.8 | V |
| I _{LI} | Input Leakage Current | 0V ≤ V _{IN} ≤ V _{CC} | -5 | 5 | μA |
| I _{LI} | MODE and ZZ Input Leakage Current ^[20] | 0V ≤ V _{IN} ≤ V _{CC} | -30 | 30 | μA |
| I _{LO} | Output Leakage Current | Output(s) disabled, 0V ≤ V _{OUT} ≤ V _{CC} | -5 | 5 | μA |
| V _{OH} | Output High Voltage ^[13] | I _{OH} = -5.0 mA | 2.4 | | V |
| V _{OL} | Output Low Voltage ^[13] | I _{OL} = 8.0 mA | | 0.4 | V |
| V _{CC} | Supply Voltage ^[13] | | 3.135 | 3.6 | V |
| V _{CCQ} | I/O Supply Voltage (3.3V) ^[13] | | 3.135 | V _{CC} | V |
| V _{CCQ} | I/O Supply Voltage (2.5V) ^[13] | | 2.375 | V _{CC} | V |

| Parameter | Description | Conditions | Typ. | -4.4 | -5 | -6 | -6.7 | Unit |
|------------------|---------------------------------------------------------|------------------------------------------------------------------------------------------------------------------------------------------------|------|------|-----|-----|------|------|
| I _{CC} | Power Supply Current: Operating ^[21, 22, 23] | Device selected; all inputs ≤ V _{IL} or ≥ V _{IH} ; cycle time ≥ t _{KC} min.; V _{CC} = Max.; outputs open | 150 | 570 | 510 | 425 | 380 | mA |
| I _{SB2} | CMOS Standby ^[22, 23] | Device deselected; V _{CC} = Max.; all inputs ≤ V _{SS} + 0.2 or ≥ V _{CC} - 0.2; all inputs static; CLK frequency = 0 | 5 | 10 | 10 | 10 | 10 | mA |
| I _{SB3} | TTL Standby ^[22, 23] | Device deselected; all inputs ≤ V _{IL} or ≥ V _{IH} ; all inputs static; V _{CC} = Max. CLK frequency = 0 | 15 | 30 | 30 | 30 | 30 | mA |
| I _{SB4} | Clock Running ^[22, 23] | Device deselected; all inputs ≤ V _{IL} or ≥ V _{IH} ; V _{CC} = Max.; CLK cycle time ≥ t _{KC} Min. | 40 | 125 | 110 | 90 | 80 | mA |

Capacitance^[15]

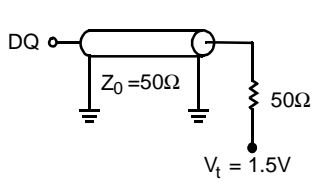
| Parameter | Description | Test Conditions | Typ. | Max. | Unit |
|----------------|-------------------------------|-------------------------------------------------------------|------|------|------|
| C _I | Input Capacitance | T _A = 25°C, f = 1 MHz, V _{CC} = 3.3V | 5 | 7 | pF |
| C _O | Input/Output Capacitance (DQ) | | 7 | 8 | pF |

Notes:

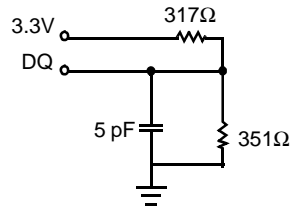
- 18. T_A is the case temperature.
- 19. Overshoot: V_{IH} ≤ +6.0V for t ≤ t_{KC} / 2
Undershoot: V_{IL} ≤ -2.0V for t ≤ t_{KC} / 2.
- 20. Output loading is specified with C_L = 5 pF as in AC Test Loads.
- 21. I_{CC} is given with no output current. I_{CC} increases with greater output loading and faster cycle times.
- 22. "Device Deselected" means the device is in Power-Down mode as defined in the truth table. "Device Selected" means the device is active.
- 23. Typical values are measured at 3.3V, 25°C, and 20 ns cycle time.

Thermal Resistance

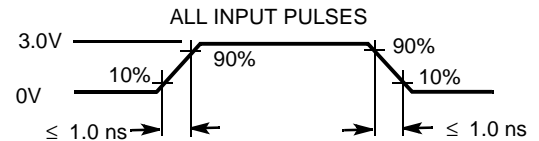
| Description | Test Conditions | Symbol | TQFP Typ. | Units |
|------------------------------------------|---------------------------------------------------------|---------------|-----------|----------------------|
| Thermal Resistance (Junction to Ambient) | Still Air, soldered on a 4.25 x 1.125 inch, 4-layer PCB | Θ_{JA} | 25 | $^{\circ}\text{C/W}$ |
| Thermal Resistance (Junction to Case) | | Θ_{JC} | 9 | $^{\circ}\text{C/W}$ |

AC Test Loads and Waveforms for 3.3V I/O


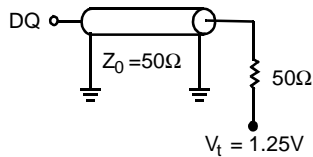
(a)



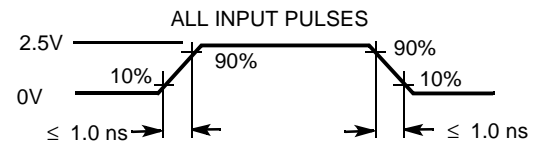
(b)



(c)

AC Test Loads and Waveforms for 2.5V I/O


(a)



(c)



Switching Characteristics Over the Operating Range^[24]

| Parameter | Description | -4.4 225 MHz | | -5 200 MHz | | -6 166 MHz | | -6.7 150 MHz | | Unit | |
|---------------------|---------------------------------------------------|-------------------------|------|---------------|------|---------------|------|-----------------|------|------|----|
| | | Min. | Max. | Min. | Max. | Min. | Max. | Min. | Max. | | |
| Clock | | | | | | | | | | | |
| t _{KC} | Clock Cycle Time | 4.4 | | 5.0 | | 6.0 | | 6.7 | | ns | |
| t _{KH} | Clock HIGH Time | 1.7 | | 2.0 | | 2.4 | | 2.6 | | ns | |
| t _{KL} | Clock LOW Time | 1.7 | | 2.0 | | 2.4 | | 2.6 | | ns | |
| Output Times | | | | | | | | | | | |
| t _{KQ} | Clock to Output Valid | V _{CCQ} = 3.3V | | 2.5 | | 3.0 | | 3.5 | | 3.5 | ns |
| | | V _{CCQ} = 2.5V | | 3.0 | | 3.5 | | 4.0 | | 4.5 | |
| t _{KQX} | Clock to Output Invalid | 1.25 | | 1.25 | | 1.25 | | 1.25 | | ns | |
| t _{KQLZ} | Clock to Output in Low-Z ^[15, 25, 26] | 0 | | 0 | | 0 | | 0 | | ns | |
| t _{KQHZ} | Clock to Output in High-Z ^[15, 25, 26] | 1.25 | 3.0 | 1.25 | 3.0 | 1.25 | 4.0 | 1.25 | 4.0 | ns | |
| t _{OEQ} | OE to Output Valid ^[27] | V _{CCQ} = 3.3V | | 2.5 | | 3.0 | | 3.5 | | 3.5 | ns |
| | | V _{CCQ} = 2.5V | | 3.0 | | 3.5 | | 4.0 | | 4.5 | |
| t _{OELZ} | OE to Output in Low-Z ^[15, 25, 26] | 0 | | 0 | | 0 | | 0 | | ns | |
| t _{OEHZ} | OE to Output in High-Z ^[15, 25, 26] | | 2.5 | | 2.5 | | 3.5 | | 3.5 | ns | |
| Set-up Times | | | | | | | | | | | |
| t _S | Address, Controls, and Data In ^[28] | 1.5 | | 1.5 | | 1.8 | | 2.0 | | ns | |
| Hold Times | | | | | | | | | | | |
| t _H | Address, Controls, and Data In ^[28] | 0.5 | | 0.5 | | 0.5 | | 0.5 | | ns | |

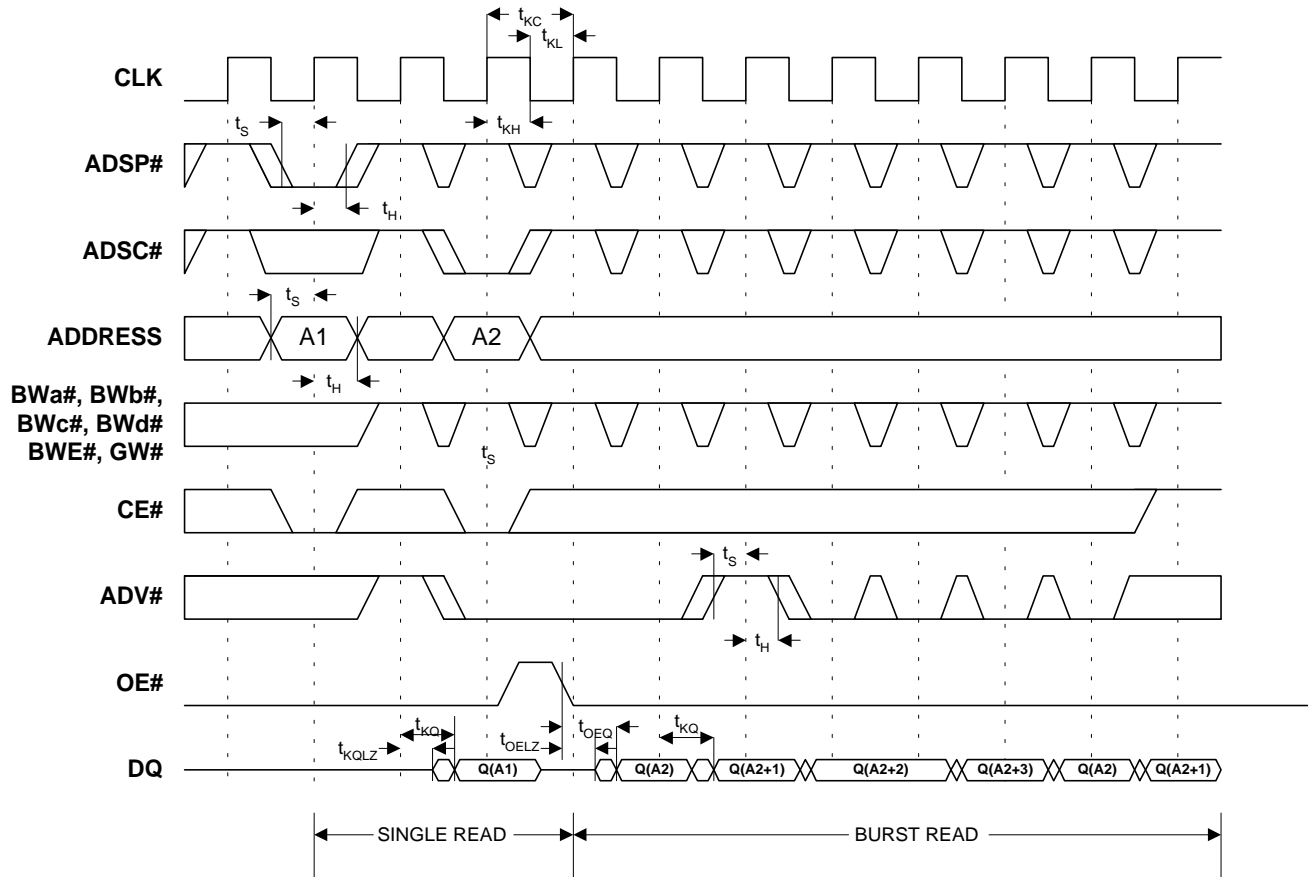
Typical Output Buffer Characteristics

| Output High Voltage | Pull-Up Current | | Output Low Voltage | Pull-Down Current | |
|---------------------|---------------------------|---------------------------|---------------------|---------------------------|---------------------------|
| V _{OH} (V) | I _{OH} (mA) Min. | I _{OH} (mA) Max. | V _{OL} (V) | I _{OL} (mA) Min. | I _{OL} (mA) Max. |
| -0.5 | -38 | -105 | -0.5 | 0 | 0 |
| 0 | -38 | -105 | 0 | 0 | 0 |
| 0.8 | -38 | -105 | 0.4 | 10 | 20 |
| 1.25 | -26 | -83 | 0.8 | 20 | 40 |
| 1.5 | -20 | -70 | 1.25 | 31 | 63 |
| 2.3 | 0 | -30 | 1.6 | 40 | 80 |
| 2.7 | 0 | -10 | 2.8 | 40 | 80 |
| 2.9 | 0 | 0 | 3.2 | 40 | 80 |
| 3.4 | 0 | 0 | 3.4 | 40 | 80 |

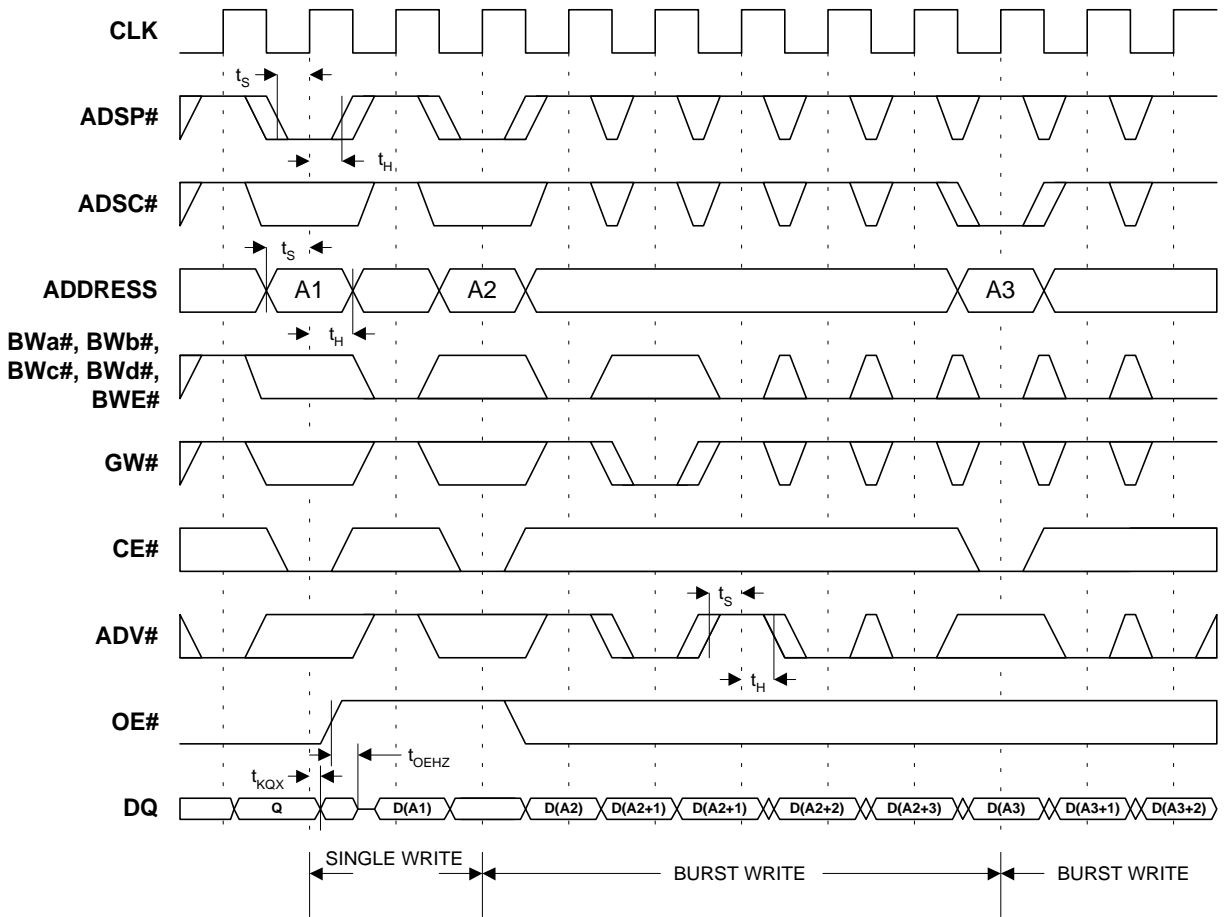
Notes:

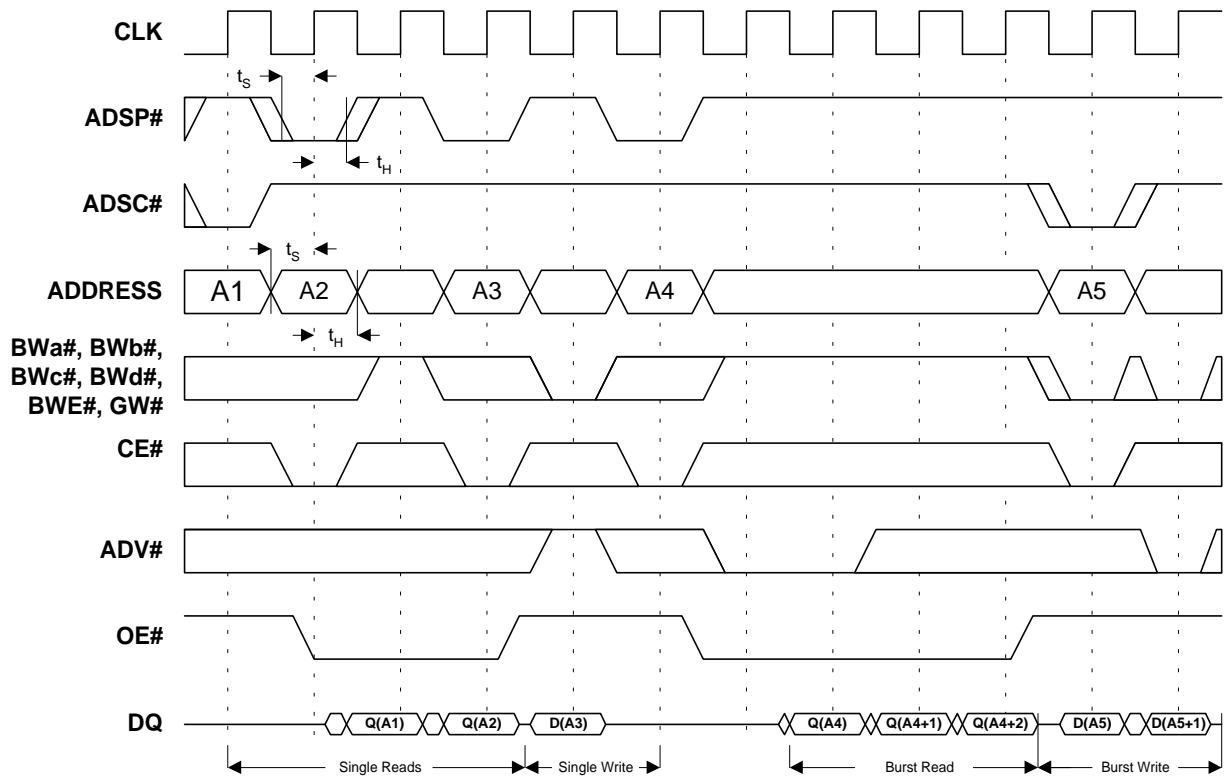
- 24. Test conditions as specified with the output loading as shown in part (a) of AC Test Loads unless otherwise noted.
- 25. Output loading is specified with C_L=5 pF as in part (a) of AC Test Loads.
- 26. At any given temperature and voltage condition, t_{KQHZ} is less than t_{KQLZ} and t_{OEHZ} is less than t_{OELZ}.
- 27. OE is a "Don't Care" when a byte write enable is sampled LOW.
- 28. This is a synchronous device. All synchronous inputs must meet specified set up and hold time, except for "Don't Care" as defined in the truth table.

Switching Waveforms

 Read Timing^[29, 30]

Notes:

29. \overline{CE} active in this timing diagram means that all chip enables \overline{CE} , CE_2 , and \overline{CE}_2 are active. \overline{CE}_2 is only available for TA package version.
30. For the X18 product, there are only BW_a and BW_b for byte write control.

Switching Waveforms (continued)
Write Timing^[29, 30]


Switching Waveforms (continued)
Read/Write Timing^[29, 30]




PRELIMINARY

**CY7C1360A/GVT71256D36
CY7C1362A/GVT71512D18**

Ordering Information

| Speed (MHz) | Ordering Code | Package Name | Package Type | Operating Range |
|-------------|---------------------------------------|--------------|-----------------------------------------------|-----------------|
| 225 | CY7C1360A-225AJC/ GVT71256D36T-4.4 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | Commercial |
| | CY7C1360A-225AC/ GVT71256D36TA-4.4 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-225BGC/ GVT71256D36B-4.4 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |
| 200 | CY7C1360A-200AJC/ GVT71256D36T-5 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-200AC/ GVT71256D36TA-5 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-200BGC/ GVT71256D36B-5 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |
| 166 | CY7C1360A-166AJC/ GVT71256D36T-6 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-166AC/ GVT71256D36TA-6 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-166BGC/ GVT71256D36B-6 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |
| 150 | CY7C1360A-150AJC/ GVT71256D36T-6.7 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-150AC/ GVT71256D36TA-6.7 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1360A-150BGC/ GVT71256D36B-6.7 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |



PRELIMINARY

**CY7C1360A/GVT71256D36
CY7C1362A/GVT71512D18**

Ordering Information (continued)

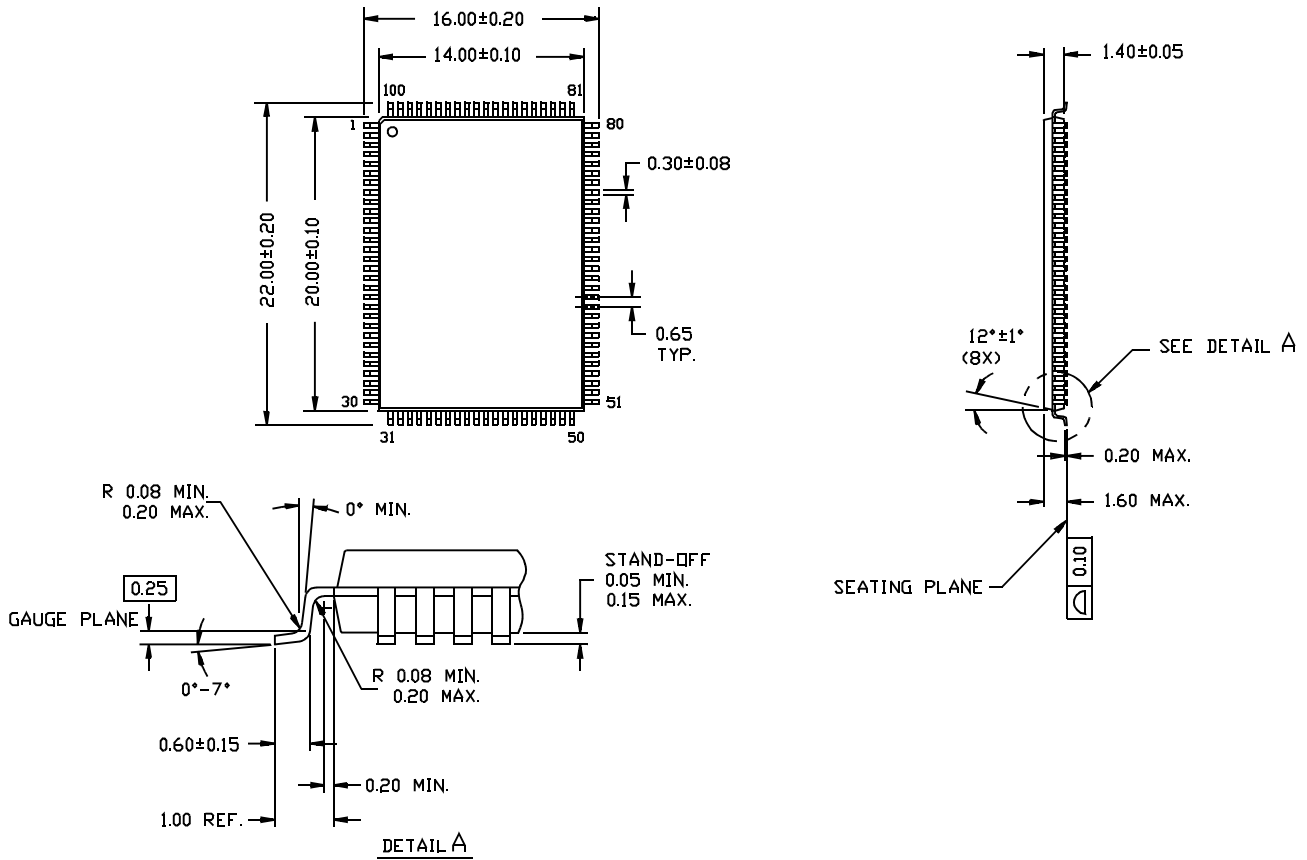
| Speed (MHz) | Ordering Code | Package Name | Package Type | Operating Range |
|-------------|---------------------------------------|--------------|-----------------------------------------------|-----------------|
| 225 | CY7C1362A-225AJC/ GVT71512D18T-4.4 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | Commercial |
| | CY7C1362A-225AC/ GVT71512D18TA-4.4 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-225BGC/ GVT71512D18B-4.4 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |
| 200 | CY7C1362A-200AJC/ GVT71512D18T-5 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-200AC/ GVT71512D18TA-5 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-200BGC/ GVT71512D18B-5 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |
| 166 | CY7C1362A-166AJC/ GVT71512D18T-6 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-166AC/ GVT71512D18TA-6 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-166BGC/ GVT71512D18B-6 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |
| 150 | CY7C1362A-150AJC/ GVT71512D18T-6.7 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-150AC/ GVT71512D18TA-6.7 | A101 | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | |
| | CY7C1362A-150BGC/ GVT71512D18B-6.7 | BG119 | 119-Lead FBGA (14 x 22 x 2.4 mm) | |

Document #: 38-00990-*A

Package Diagrams

100-Pin Thin Plastic Quad Flatpack (14 x 20 x 1.4 mm) A101

DIMENSIONS ARE IN MILLIMETERS.

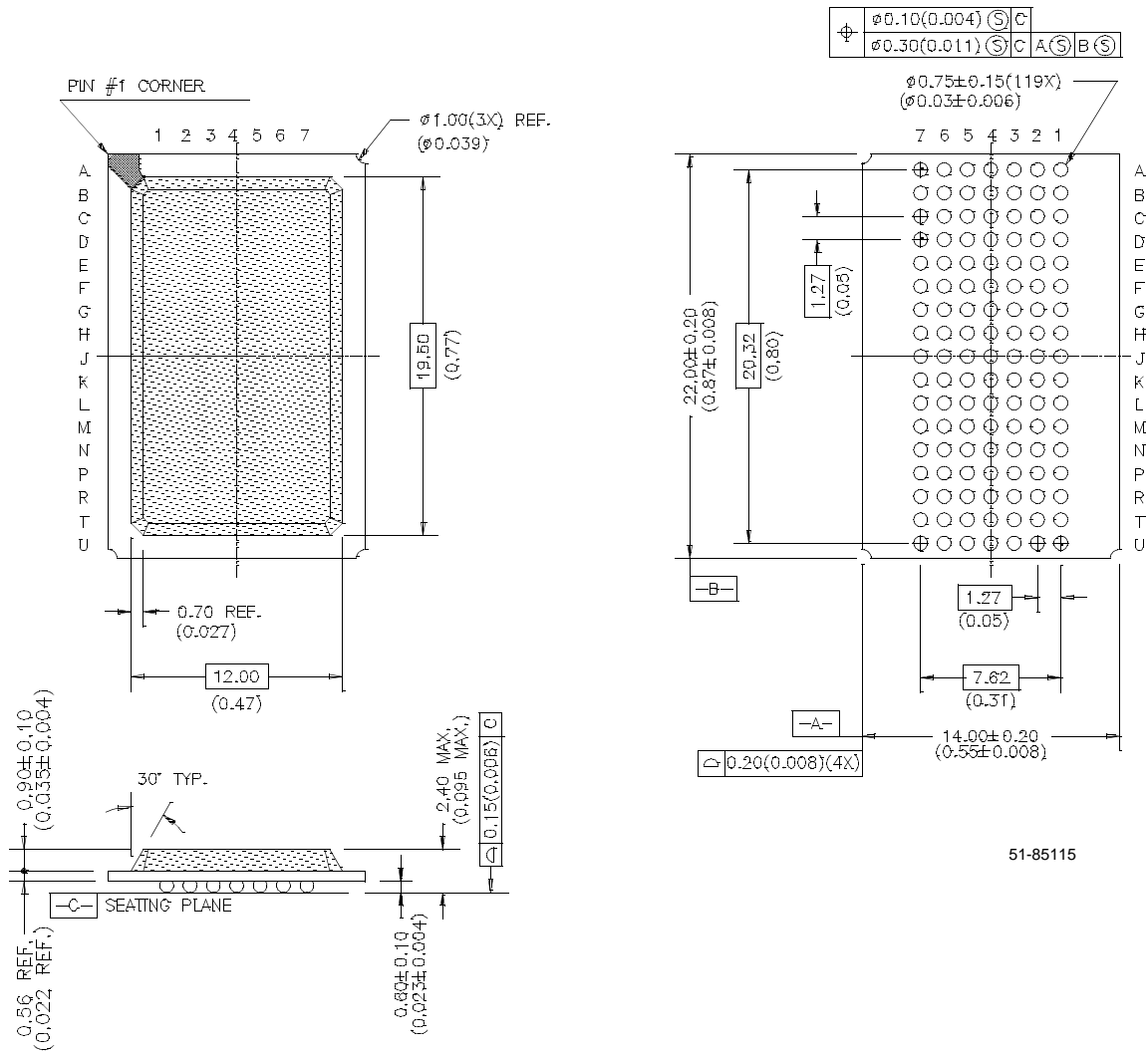


51-85050-A

Package Diagrams (continued)

119-Lead FBGA (14 x 22 x 2.4 mm) BG119

DIMENSION IN MILLIMETERS (INCHES)



51-85115